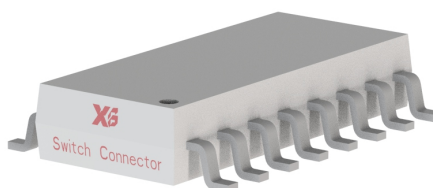


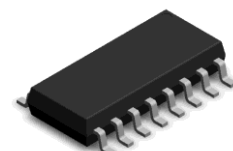
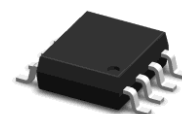
8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series



Features:

- Halogens free
- Current transfer ratio
(CTR: 50~600% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 8 Pin SSOP with a 2.0 mm profile
- Pb free and RoHS compliant.
- UL approved (E214129)
- VDE approved (40028116)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved



Description

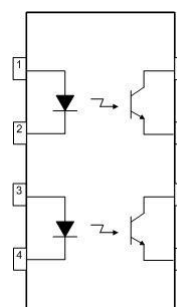
The ELD3H7 and ELQ3H7 contains of an infrared emitting diode optically coupled to a phototransistor detector encapsulated with green compound.

ELD3H7 offers 2 channels in a 8-pin small outline SMD package, while ELQ3H7 offers 4 channels in a 16-pin small outline SMD package.

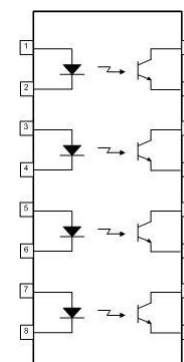
Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

Schematic



1, 3 Anode
2, 4 Cathode
5, 7 Emitter
6, 8 Collector



1, 3, 5, 7 Anode
2, 4, 6, 8 Cathode
9, 11, 13, 15 Emitter
10, 12, 14, 16 Collector

8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Absolute Maximum Ratings (T_a=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P _D	70	mW
Output	Power dissipation	P _C	150	mW
	Collector current	I _C	50	mA
	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
Total power dissipation		P _{TOT}	200	mW
Isolation voltage ^{*1}		V _{ISO}	3750	V rms
Operating temperature		T _{OPR}	-55 ~ +110	°C
Storage temperature		T _{STG}	-55 ~ +125	°C
Soldering temperature ^{*2}		T _{SOL}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, LED side pins shorted together, and detector side pins shorted together.

*2 For 10 seconds.

8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Electrical Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	$I_F = 20\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 4\text{V}$
Input capacitance	C_{in}	-	30	250	pF	$V = 0, f = 1\text{kHz}$

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	CTR	50	-	600	%	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$

Transfer Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	0.1	0.2	V	$I_F = 10\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	-	-	Ω	$V_{IO} = 500\text{Vdc}, 40\sim 60\% \text{ R.H.}$
Floating capacitance	C_{IO}	-	0.3	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$
Rise time	t_r	-	5	18	μs	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$
Fall time	t_f	-	3	18	μs	

* Typical values at $T_a = 25^{\circ}\text{C}$

8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

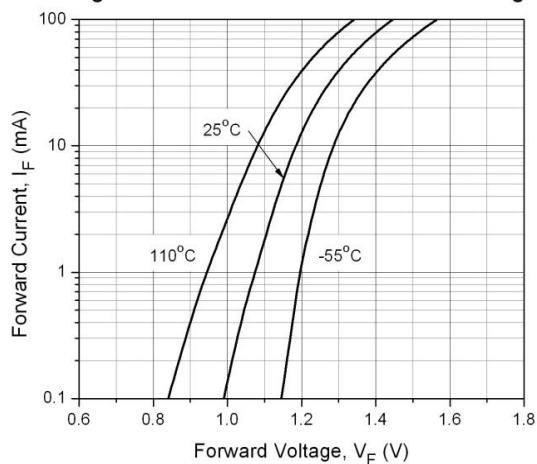


Figure 2. Normalized Collector Current vs Forward Current

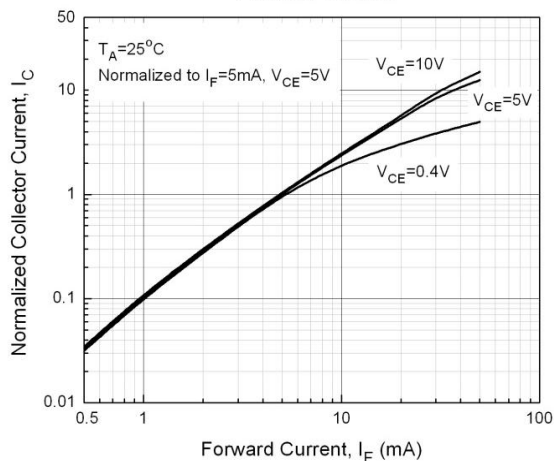


Figure 3. Normalized Current Transfer Ratio vs Forward Current

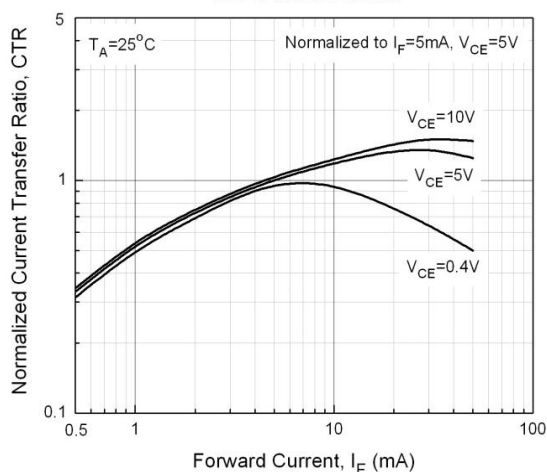


Figure 4. Normalized Collector Current vs Ambient Temperature

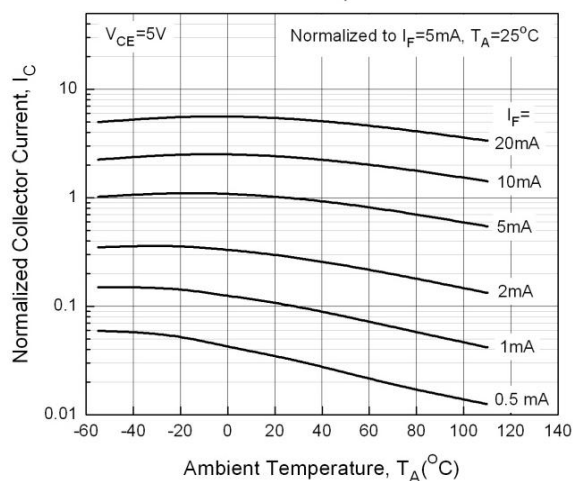


Figure 5. Normalized Current Transfer Ratio vs Ambient Temperature

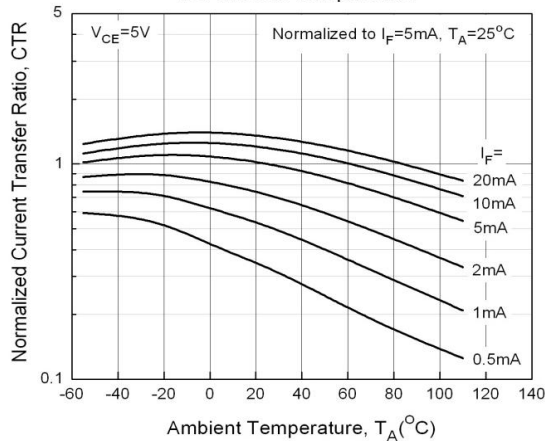
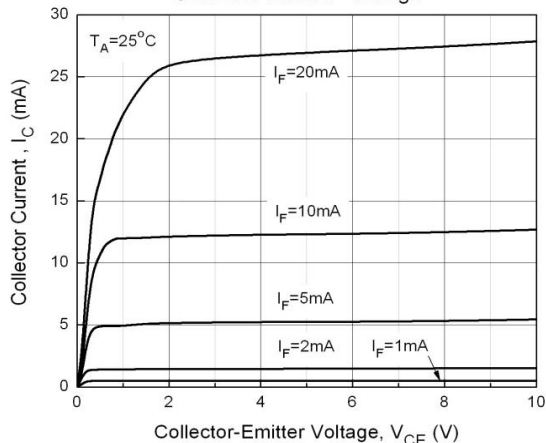


Figure 6. Collector Current vs Collector-Emitter Voltage



8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Figure 7. Collector Current vs Collector-Emitter Voltage

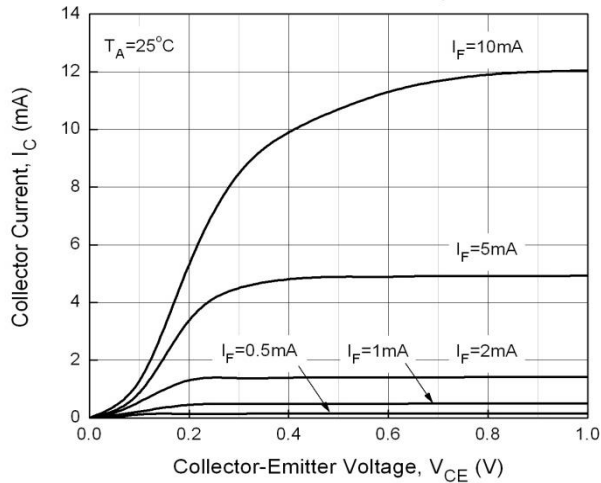


Figure 8. Collector Dark Current vs Ambient Temperature

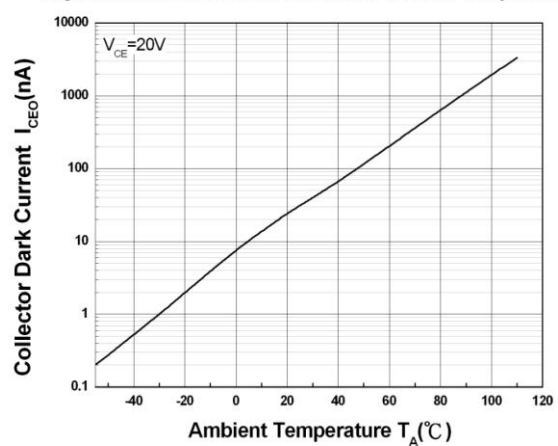


Figure 9. Collector-Emitter Saturation Voltage vs Ambient Temperature

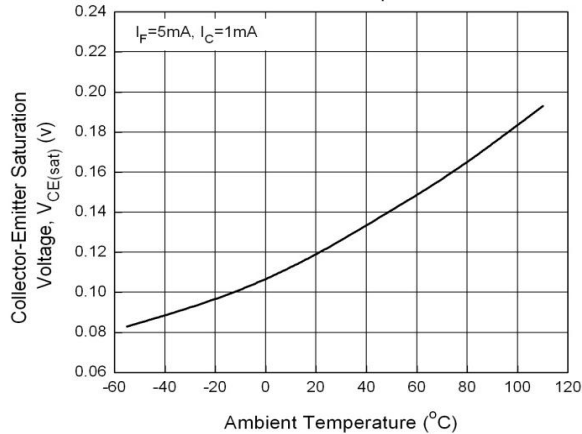


Figure 10. Switching Time vs Load Resistance

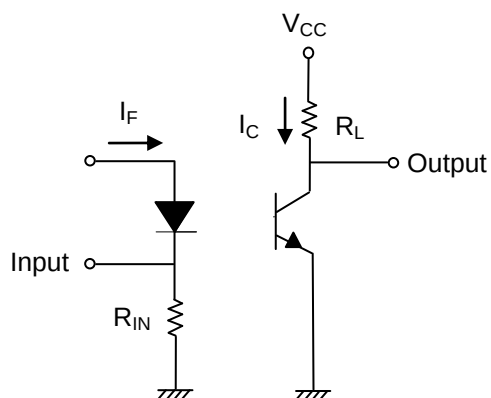
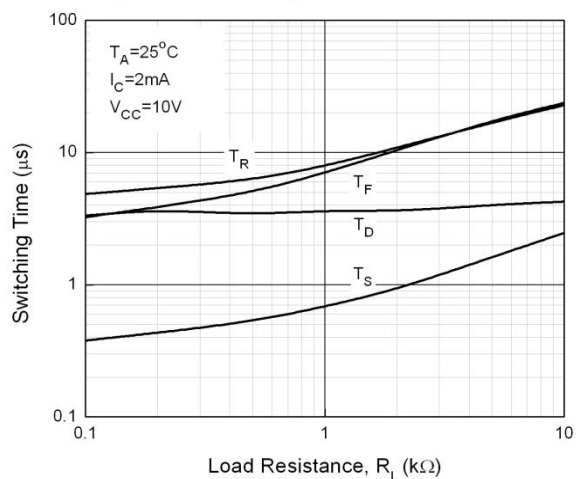


Figure 11. Switching Time Test Circuit & Waveforms

8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Order Information

Part Number

ELD3H7(Z)-V, ELQ3H7(Z)-V

Note

D3H7, Q3H7 = Part No.

Z = Tape and reel option (TA or none).

V = VDE (optional)

Option	Description	Packing quantity
None	Tube option of ELD3H7	80 units per tube
(TA)	Tape & reel option of ELD3H7	1000 units per reel
None	Tube option of ELQ3H7	40 units per tube
(TA)	Tape & reel option of ELQ3H7	1000 units per reel

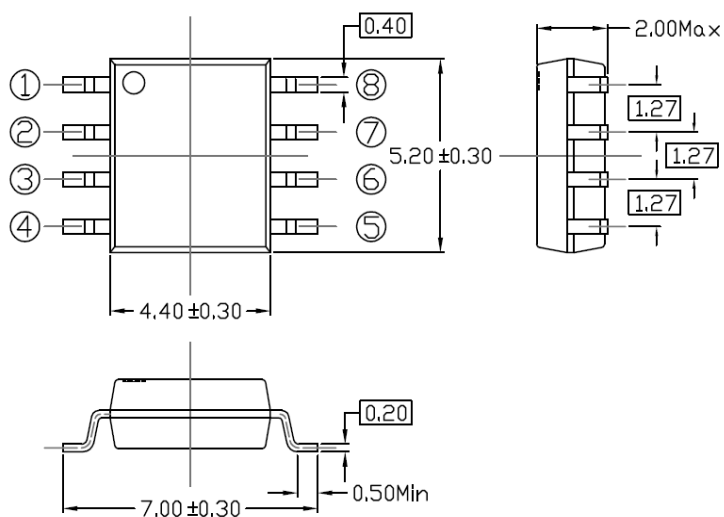
8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

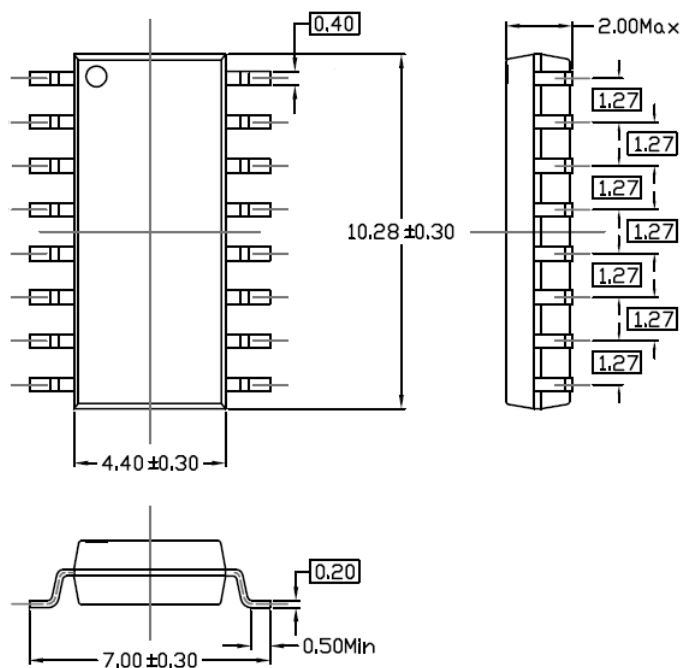
Package Drawing

(Dimensions in mm)

ELD3H7



ELQ3H7

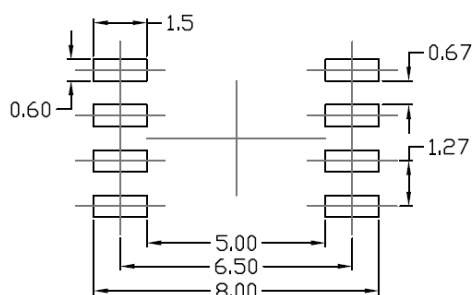


8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

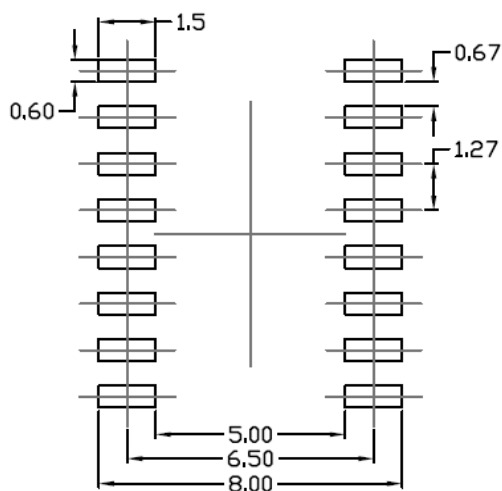
ELD3H7 ELQ3H7 Series

Recommended pad layout for surface mount leadform

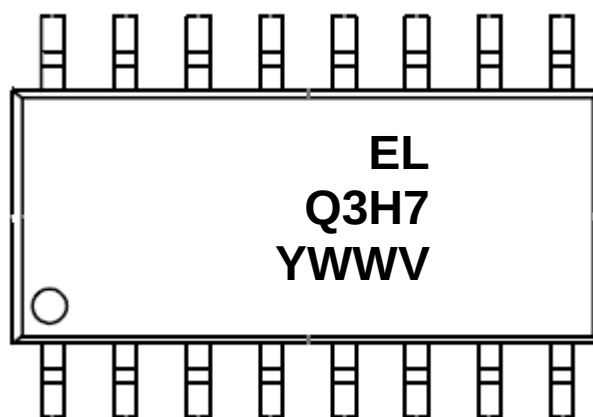
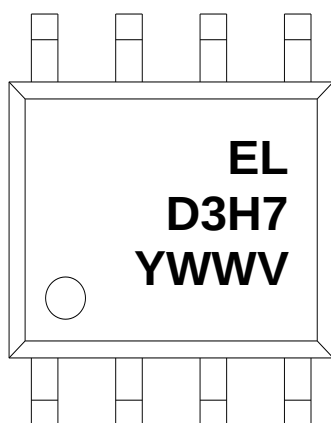
ELD3H7



ELQ3H7



Device Marking



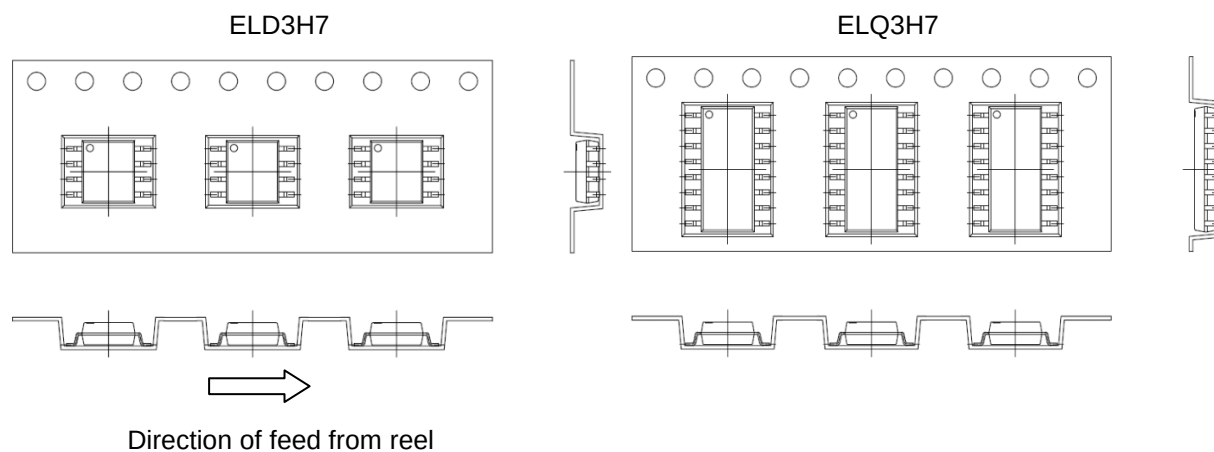
Notes

EL	denotes XI
Q3H7 D3H7	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

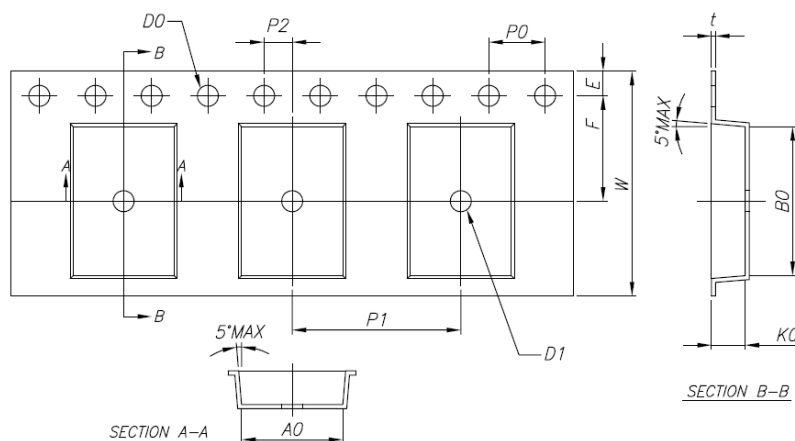
8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Tape & Reel Packing Specifications



Tape dimensions

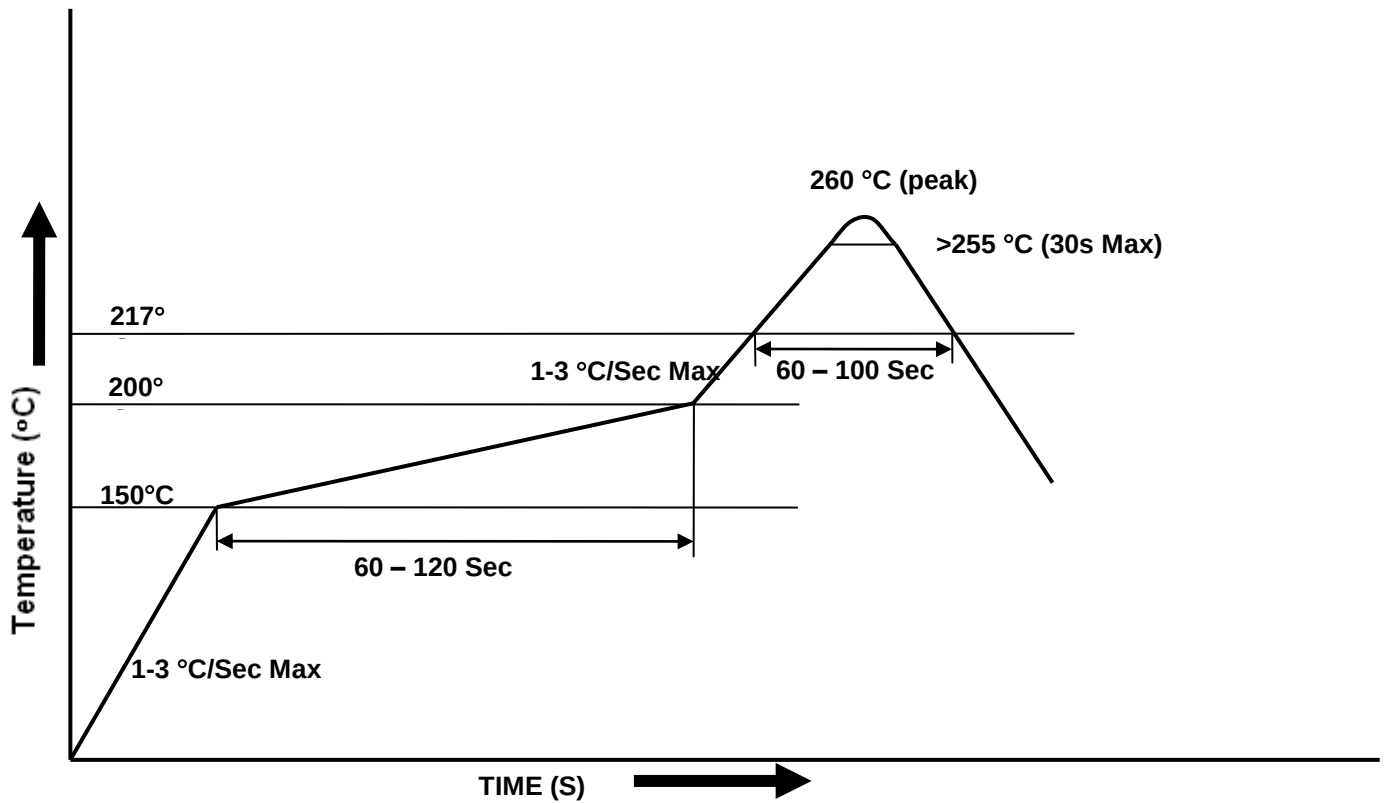


Dimension No.		A0	B0	D0	D1	E	F
Dimension (mm)	D3H7	7.4±0.1	5.6±0.1	1.5+0.1 -0	1.5+0.1 -0	1.75±0.1	7.5±0.1
	Q3H7	7.2±0.1	10.6±0.1	1.5+0.1 -0	1.5+0.1 -0	1.75±0.1	7.5±0.1
Dimension No.		P0	P1	P2	t	W	K0
Dimension (mm)	D3H7	4.0±0.1	12.0±0.1	2.0±0.1	0.3±0.05	16.0±0.3	2.4±0.1
	Q3H7	4.0±0.1	12.0±0.1	2.0±0.1	0.3±0.05	16.0±0.3	2.4±0.1

8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

Solder Reflow Temperature Profile



8PIN 16 PIN ULTRA SMALL SSOP PHOTOTRANSISTOR PHOTOCOUPLER

ELD3H7 ELQ3H7 Series

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